TCXO ME32T

nA Current 32.768 KHz

± 5 ppm -40 to 85 °C

CMOS

SMD

15 pF

1.8 V 2.5 V 3.3 V 5.0 V

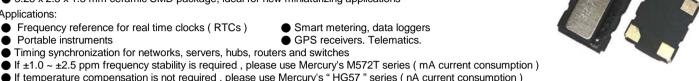
3.0 V

Features

- CMOS 32.768 KHz TCXO with a maximum frequency stability of \pm 5 ppm (±2.62 minutes / year) over -40 to +85°C, providing a much better timekeeping accuracy than the competition
- A proprietary temp. compensation technique is applied to the built-in 32.768 KHz tuning fork crystal & temp. sensor
- A 1.5 μA typical current consumption makes it ideal for battery-operated devices.
- 3.28 x 2.5 x 1.3 mm ceramic SMD package, ideal for new miniaturizing applications

Applications:

- If temperature compensation is not required, please use Mercury's "HG57" series (nA current consumption) or "HA" series (mA current consumption)



General specifications of all available packages, at Ta=+25°C, CL=15pF

Output Wave Form			Square wave [CMOS]				
Nominal Frequency			32.768 KHz				
Standard Supply Voltages V _{DD}		1.8 ± 5 %	2.5 ± 5 %	3.0 ± 5 %	3.3 ± 5 %	5.0 ± 10 %	
(Custom V _{DD} is also available)		Voltage code	18	25	3	33	5
Power Supply Current (lcc) (typical)			0.79 uA	1.05 uA	1.25 uA	1.37 uA	2.05 uA
Initial Calibration Tolerance			\pm 1.5 ppm (max.) at T _{amb} = +25 $^{\circ}$ C \pm 3 $^{\circ}$ C				
			± 3.8 ppm (-10°C to +60°C)				
Frequency Stability over Temperature (max.)			± 5 ppm (-40°C to +85°C)				
			± 8 ppm (-40°C to +105°C)				
Timing error over time [± 5 ppm (-40°C to +85°C)]			± 0.432 sec/day ; ± 12.960 sec/month ; ± 2.628 minutes / year , w.r.t fo at +25°C.				
Frequency Stability	vs Aging		± 3.0 ppm / year (max.) first year at +25° C				
	vs V _{DD} Tolerance Change		\pm 0.2 ppm (max.) for a \pm 5 % input voltage change				
	vs Load Change		± 0.2 ppm (max.) for a ± 10 % loading condition change				
	vs Reflow		± 1.0 ppm (max.) 1 reflow and measured 24 hours afterwards				
	vs all range of V_{DD} ($\triangle f / V$)		\pm 1.0 ppm / volt (max.) V_{DD} = 1.7 V to 5.5 V .				
Output Logic / Output Load			CMOS / 15 pF				
Supply Voltage Variation ($\triangle V_{DD}$)			0.25 V (max.) Condition : \triangle V / \triangle t = 1 V / us				
Output Voltage Level V _{OH}			V_{DD} - 0.4 V (min.) ; I_{OH} = 0.1 mA , all V_{DD} range				
Output Voltage Level V _{OL}			0.4 V (max.) ; I_{OL} = - 0.1 mA , all V_{DD} range				
Start - up	Time		1 sec. (max.) at +25°C ; 3 sec. (max .) over -40°C to +85°C				
Rise Time	e and Fall Time		100 nano. sec. max. Measured at 20% ←→ 80% of the waveform , 15 pF load.				
Duty Cyc	le		50% ±10% typical				
Pad 1 OE	Thresholds		$Vih = 0.8 * V_{DD}$, $Vil = 0.2 * V_{DD}$; Open connection prohibit				

